

1. Applications

- Automotive
- Relay Drivers
- DC-DC Converters
- Motor Drivers

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 2.8 \text{ m}\Omega \text{ (typ.)} (V_{GS} = -10 \text{ V})$
- (2) Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -40 \ V)$
- (3) Enhancement mode: V_{th} = -2.0 to -3.0 V (V_{DS} = -10 V, I_D = -1 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics			Rating	Unit
Drain-source voltage		V _{DSS}	-40	V
Gate-source voltage		V _{GSS}	-20/+10	
Drain current (DC)	(Note 1)	I _D	-100	A
Drain current (pulsed)	(Note 1)	I _{DP}	-300	
Power dissipation (T _c = 2	:5°C)	PD	250	W
Single-pulse avalanche energy	(Note 2)	E _{AS}	338	mJ
Avalanche current		I _{AR}	-100	А
Channel temperature	(Note 3)	T _{ch}	175	°C
Storage temperature	(Note 3)	T _{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	0.6	°C/W

Note 1: Ensure that the channel temperature does not exceed 175°C.

Note 2: V_{DD} = -25 V, T_{ch} = 25°C (initial), L = 35 μ H, R_G = 25 Ω , I_{AR} = -100 A

Note 3: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = -16/+10 V, V _{DS} = 0 V		_	±10	μA
Drain cut-off current	I _{DSS}	V _{DS} = -40 V, V _{GS} = 0 V	_	_	-10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = -10 mA, V _{GS} = 0 V	-40	_	_	V
Drain-source breakdown voltage (Note 4)	V _{(BR)DSX}	I _D = -10 mA, V _{GS} = 10 V	-30	_	—	
Gate threshold voltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	-2.0	_	-3.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = -6 V, I _D = -50 A		3.4	5.4	mΩ
		V _{GS} = -10 V, I _D = -50 A		2.8	3.6	

Note 4: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	_	9500	_	pF
Reverse transfer capacitance	C _{rss}			1000	—	
Output capacitance	C _{oss}			1550	_	
Switching time (rise time)	t _r	See Fig. 6.2.1	_	10	—	ns
Switching time (turn-on time)	t _{on}			20	—	
Switching time (fall time)	t _f			270	—	
Switching time (turn-off time)	t _{off}			1150	—	



Duty \leq 1%, t_w = 10 μ s

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx -32$ V, V_{GS} = -10 V, I_D = -100 A	—	250	_	nC
Gate-source charge 1	Q _{gs1}		_	185	—	
Gate-drain charge	Q _{gd}			65	—	

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 5)	I _{DR}	—	_	—	-100	A
Reverse drain current (pulsed)	(Note 5)	I _{DRP}		_	—	-300	
Diode forward voltage		V _{DSF}	I _{DR} = -100 A, V _{GS} = 0 V	—	—	1.2	V
Reverse recovery time		t _{rr}	I _{DR} = -100 A, V _{GS} = 0 V	_	80	_	ns
Reverse recovery charge		Q _{rr}	dl _{DR} /dt = 50 A/µs		84	_	nC

Note 5: Ensure that the channel temperature does not exceed 175°C.



7. Marking (Note)



Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]] Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.



8. Moisture-Proof Packing

This device is packed in a moisture-proof laminated aluminum bag.

8.1. Precautions for Transportation and Storage (Note)

- (1) Avoid excessive vibration during transportation.
- (2) Do not toss or drop the packed devices to avoid ripping of the bag.
- (3) After opening the moisture-proof bag, the devices should be assembled within two weeks in an environment of 5°C to 30°C and RH70% or below. Perform reflow at most twice.
- (4) The moisture-proof bag may be stored unopened for up to 24 months at 5°C to 30°C and RH90% or below.
- (5) If, upon opening the bag, the moisture indicator card shows humidity of 30% or above (the color of the 30% dot has changed from blue to pink) or the expiration date has passed, the devices should be baked as follows:

Baking conditions: 125°C for 48 hours.

Note: Since the tape materials are not heat-proof, devices should be placed on either heat-proof trays or aluminum magazines when baking.



The humidity indicator shows an approximate ambient humidity at 25° C. If the ambient humidity is below 30%, the color of all the indicator dots is blue. If, upon opening the bag, the color of the 30% dot has changed from blue to pink, the devices should be baked before assembly.

Fig. 8.1.1 Humidity Indicator



9. Characteristics Curves (Note)













Fig. 9.10 Dynamic Input/Output Characteristics







Package Dimensions





Weight: 1.07 g (typ.)

Package Name(s)	
TOSHIBA: 2-10W1S	
Nickname: TO-220SM(W)	